

APPLICATION DATA SHEET

APPLICATION INFORMATION

Application Type::	REGULAR
Subject Matter::	UTILITY
CD-ROM or CD-R?::	NONE
Title::	SEMICONDUCTOR DEVICE INCLUDING TRANSISTORS FORMED IN SEMICONDUCTOR LAYER HAVING SINGLE-CRYSTAL STRUCTURE ISOLATED FROM SUBSTRATE AND FABRICATION METHOD OF THE SAME
Attorney Docket Number::	248183US2
Total Drawing Sheets::	34

INVENTOR INFORMATION

Applicant Authority Type::	INVENTOR
Primary Citizenship Country::	Japan
Status::	FULL CAPACITY
Given Name::	Tomoaki
Family Name::	SHINO
City of Residence::	Kawasaki-shi
Country of Residence::	Japan
Street of Mailing Address::	c/o Intellectual Property Division, Toshiba Corporation, 1-1, Shibaura 1-chome, Minato-ku,
City of Mailing Address::	Tokyo
Country of Mailing Address::	Japan
Postal or Zip Code of Mailing Address::	105-8001

CORRESPONDENCE INFORMATION

Correspondence Customer Number::	22850
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REPRESENTATIVE INFORMATION

Representative Customer Number::	22850
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FOREIGN PRIORITY INFORMATION

Application Number:	Country::	Filing Date::	Priority Claimed::
2003-394321	Japan	11/25/03	YES

ASSIGNMENT INFORMATION

Assignee Name:: KABUSHIKI KAISHA TOSHIBA
 Street of Mailing Address:: 1-1, Shibaura, 1-chome,
 Minato-ku,
 City of Mailing Address:: Tokyo
 Country of Mailing Address:: Japan
 Postal or Zip Code of Mailing Address:: 105-8001